



DMMT3906W

40V MATCHED PAIR PNP SMALL SIGNAL TRANSISTOR IN SOT363

Features

- BV_{CEO} > -40V
- I_C = -200mA High Collector Current
- Pair of PNP Transistors That Are Intrinsically Matched (Note 1)
- 2% Matching on Current Gain (h_{FE})
- 2mV Matching on Base-Emitter Voltage (V_{BE})
- Fully Internally Isolated in a Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 2 & 3)
- Halogen and Antimony Free. "Green" Device (Note 4)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 5)

Mechanical Data

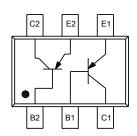
- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)

Applications

- Current Mirrors
- Differential and Instrumentation Amplifiers
- Comparators



Top View



Device Schematic and Pin-Out Top View

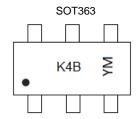
Ordering Information (Notes 5 & 6)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DMMT3906W-7-F	AEC-Q101	K4B	7	8	3,000
DMMT3906WQ-7-F	Automotive	K4B	7	8	3,000

Notes:

- 1. Intrinsically matched pair as this is built with adjacent die from the same wafer.
- 2. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 3. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 4. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 5. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 6. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K4B = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018) M = Month (ex: 2 = February)

Date Code Key

Year	2017	2018	2019	2020	2021	2022	2023	2	024	2025	2026	2027	2028
Code	Е	F	G	Н	ı	J	K		L	М	N	0	Р
Month	Jan	Feb	Mar	Apr	May	/ Ju	n J	ul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6		7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current	Ic	-200	mA

Thermal Characteristics – Total Device (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7) Total Device	P_{D}	200	mW
Thermal Resistance, Junction to Ambient (Note 7)	$R_{ heta JA}$	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

Thermal Characteristics - Total Device

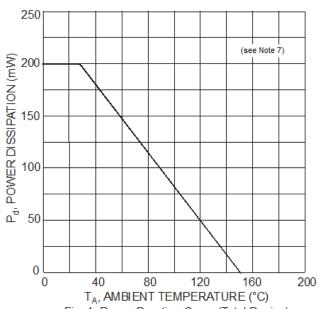


Fig. 1, Power Derating Curve (Total Device)

^{7.} For a device mounted on minimum recommended pad layout with 1oz copper that is on a single-sided 1.6mm FR4 PCB; the device is measured under still air conditions whilst operating in a steady-state.

^{8.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Electrical Characteristics (@TA = +25°C unless otherwise specified)

Characteristic	Symbol	Min	TYP	Max	Unit	Test Condition
OFF CHARACTERISTICS						1
Collector-Base Breakdown Voltage	BV _{CBO}	-40	_	_	V	$I_C = -100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-40	_	_	V	$I_C = -1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	-5.0	_	_	V	I _E = -100μA, I _C = 0
Collector Cutoff Current	I _{CEX}	_	_	-50	nA	V _{CE} = -30V, V _{EB(OFF)} = 3.0V
Base Cutoff Current	I _{BL}	_	_	-50	nA	V _{CE} = -30V, V _{EB(OFF)} = 3.0V
ON CHARACTERISTICS (Note 9)						•
DC Current Gain	h _{FE}	60 80 100 60 30	_	 300 	_	$\begin{split} I_{C} &= -100\mu\text{A}, V_{CE} = -1.0V \\ I_{C} &= -1.0\text{mA}, V_{CE} = -1.0V \\ I_{C} &= -10\text{mA}, V_{CE} = -1.0V \\ I_{C} &= -50\text{mA}, V_{CE} = -1.0V \\ I_{C} &= -100\text{mA}, V_{CE} = -1.0V \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	_	-250 -400	mV	$I_C = -10$ mA, $I_B = -1.0$ mA $I_C = -50$ mA, $I_B = -5.0$ mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	0.65 —	_	-850 -950	mV	$I_C = -10\text{mA}, I_B = -1.0\text{mA}$ $I_C = -50\text{mA}, I_B = -5.0\text{mA}$
MATCHING CHARACTERISTICS	1 1				1	
DC Current Gain Matching (Note 10)	h _{FE1} / h _{FE2}		1	2	%	$I_C = -2mA$, $V_{CE} = -5V$
Base-Emitter Voltage Matching (Note 11)	V _{BE1} - V _{BE2}	_	1	2	mV	$I_C = -2mA$, $V_{CE} = -5V$
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(SAT)1} / V _{CE(SAT)2}	_	1	2	%	I _C = -10mA, I _B = -1.0mA
Base-Emitter Saturation Voltage (Note 10)	V _{BE(SAT)1} / V _{BE(SAT)2}	_	1	2	%	I _C = -10mA, I _B = -1.0mA
SMALL SIGNAL CHARACTERISTICS						•
Output Capacitance	C _{OBO}	_	_	4.5	pF	$V_{CB} = -5.0V$, $f = 1.0MHz$, $I_E = 0$
Input Capacitance	C _{IBO}	_	_	10.0	pF	$V_{EB} = -0.5V$, $f = 1.0MHz$, $I_C = 0$
Input Impedance	h _{IE}	2.0	_	12	kΩ	
Voltage Feedback Ratio	h _{RE}	0.1	_	10	x 10 ⁻⁴	$V_{CE} = 10V, I_{C} = 1.0mA,$
Small Signal Current Gain	h _{FE}	100	_	400	_	f = 1.0kHz
Output Admittance	hoE	3.0	_	60	μS	
Current Gain-Bandwidth Product	f _T	250	_	_	MHz	$V_{CE} = -20V, I_{C} = -10mA,$ f = 100MHz
Noise Figure	NF	_		4.0	dB	$V_{CE} = -5.0V$, $I_{C} = -100\mu A$, $R_{S} = 1.0k\Omega$, $f = 1.0kHz$
SWITCHING CHARACTERISTICS						
Delay Time	t _D	_	_	35	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$
Rise Time	t _R			35	ns	$V_{BE(OFF)} = 0.5V, I_{B1} = -1.0mA$
Storage Time	t _S			225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$
Fall Time	t _F	_	_	75	ns	$I_{B1} = I_{B2} = -1.0 \text{mA}$

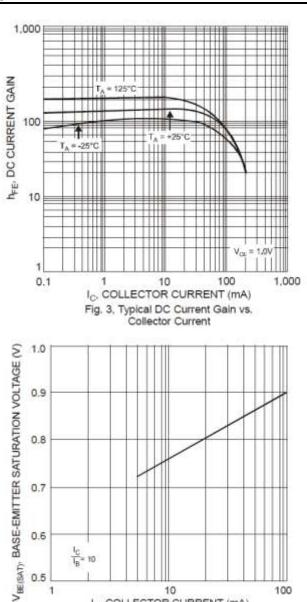
Notes:

^{9.} Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%. 10. Is the ratio of one transistor compared to the other transistor.

^{11.} V_{BE1} - V_{BE2} is the absolute difference of one transistor compared to the other transistor.



Typical Electrical Characteristics (@TA = +25°C unless otherwise specified.)



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I_C. COLLECTOR CURRENT (mA) Fig. 5, Typical Base-Emitter Saturation Voltage vs. Collector Current

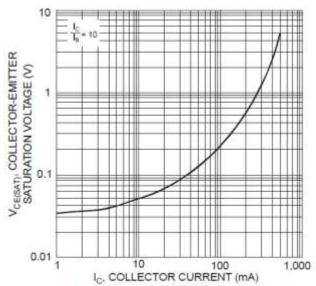


Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current

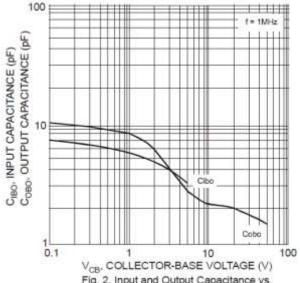


Fig. 2, Input and Output Capacitance vs. Collector-Base Voltage

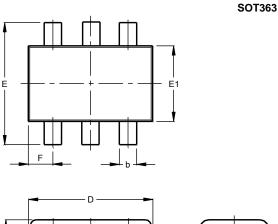
0.5

100



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



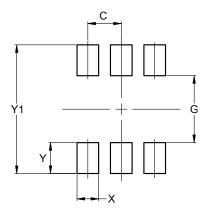
	SOT363							
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	1.00					
b	0.10	0.30	0.25					
С	0.10	0.22	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C).650 B	SC					
F	0.40	0.45	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	All Dimensions in mm							

	D		<u>. </u>
			
A2			
L	- e -	c	a

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



Dimensions	Value (in mm)
С	0.650
G	1.300
X	0.420
Y	0.600
Y1	2.500



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